

ABSTRACT OF THE DISCLOSURE

To provide a low-profile EL device, a method for manufacturing the same, and a low-profile electronic apparatus. An EL device 10 includes first electrodes 30, EL layers 40 disposed on the first electrodes 30, a second electrode 50 to cover the EL layers 40, and a barrier layer 52 in direct contact with the second electrode 50. At least the surface of the second electrode 50 facing the barrier layer 52 is composed of an inorganic oxide. At least the surface of the barrier layer 52 facing the second electrode 50 is composed of an inorganic compound.